## NSN 5961-01-285-4722

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View Online at https://aerobasegroup.com/nsn/5961-01-285-4722 **Inclosure Material:** Metal **Overall Length:** 37.0 millimeters **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 14.0 millimeters **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage and 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 25.00 amperes drain current universal and 0.10 amperes drain current absolute **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0